Data Sheet September 17, 2015 FN3976.4

Half Amp Full Bridge Power Driver for Small 3V, 5V and 12V DC Motors

In the Functional Block Diagram of the HIP4020, the four switches and a load are arranged in an H-Configuration so that the drive voltage from terminals OUTA and OUTB can be cross-switched to change the direction of current flow in the load. This is commonly known as 4-quadrant load control. As shown in the Block Diagram, switches Q1 and Q4 are conducting or in an ON state when current flows from V_{DD} through Q1 to the load, and then through Q4 to terminal V_{SSB}; where load terminal OUTA is at a positive potential with respect to OUTB. Switches Q1 and Q4 are operated synchronously by the control logic. The control logic switches Q3 and Q2 to an open or OFF state when Q1 and Q4 are switched ON. To reverse the current flow in the load, the switch states are reversed where Q1 and Q4 are OFF while Q2 and Q3 are ON. Consequently, current then flows from V_{DD} through Q3, through the load, and through Q2 to terminal V_{SSA}, and load terminal OUTB is then at a positive potential with respect to OUTA.

Terminals ENA and ENB are ENABLE Inputs for the Logic A and B Input Controls. The ILF output is an Overcurrent Limit Fault Flag Output and indicates a fault condition for either Output A or B or both. The V_{DD} and V_{SS} are the Power Supply reference terminals for the A and B Control Logic Inputs and ILF Output. While the V_{DD} positive power supply terminal is internally connected to each bridge driver, the V_{SSA} and V_{SSB} Power Supply terminals are separate and independent from V_{SS} and may be more negative than the V_{SS} ground reference terminal. The use of level shifters in the gate drive circuitry to the NMOS (low-side) output stages allows controlled level shifting of the output drive relative to ground.

Features

- Two Independent Controlled Complementary MOS Power Output Half H-Drivers (Full-Bridge) for Nominal 3V to 12V Power Supply Operation
- Split ±Voltage Power Supply Option for Output Drivers
- Load Switching Capabilities to 0.5A
- Single Supply Range +2.5V to +15V
- Low Standby Current
- CMOS/TTL Compatible Input Logic
- Over-Temperature Shutdown Protection
- Overcurrent Limit Protection
- Overcurrent Fault Flag Output
- Direction, Braking and PWM Control
- Pb-Free Plus Anneal Available (RoHS Compliant)

Applications

- DC Motor Driver
- Relay and Solenoid Drivers
- Stepper Motor Controller
- Air Core Gauge Instrument Driver
- Speedometer Displays
- Tachometer Displays
- Remote Power Switch
- Battery Operated Switch Circuits
- Logic and Microcontroller Operated Switch

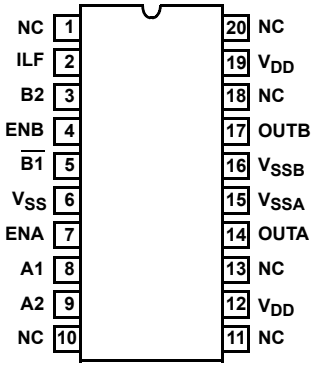
Ordering Information

PART NUMBER	PART MARKING	TEMP. RANGE (°C)	PACKAGE	PKG. DWG. #
HIP4020IB **(No longer available, recommended replacement: HIP4020IBZ)**	HIP4020IB	-40 to 85	20 Ld SOIC	M20.3
HIP4020IBZ (Note)	HIP4020IBZ	-40 to 85	20 Ld SOIC (Pb-free)	M20.3
HIP4020IBZT (Note)	HIP4020IBZ	-40 to 85	20 Ld SOIC Tape and Reel (Pb-free)	M20.3

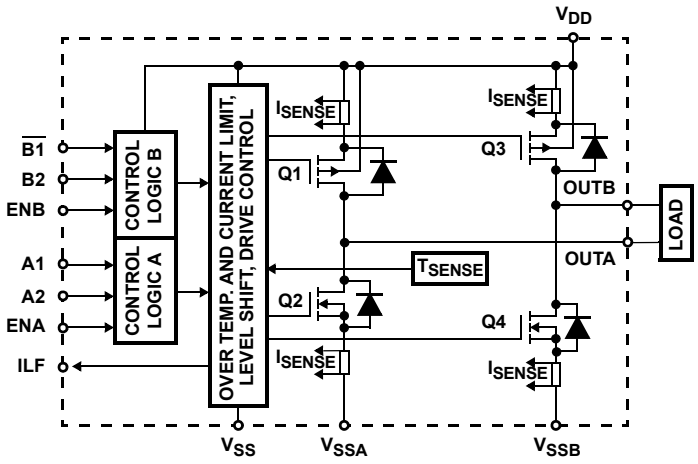
NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Pinout

HIP4020 (SOIC)
TOP VIEW



Block Diagram



Absolute Maximum Ratings

Supply Voltage; V_{DD} to V_{SS} or V_{SSA} or V_{SSB} . . . . . +15V
Neg. Output Supply Voltage, (V_{SSA}, V_{SSB}) . . . . . (Note 1)
DC Logic Input Voltage (Each Input) . . . (V_{SS} -0.5V) to (V_{DD} +0.5V)
DC Logic Input Current (Each Input) . . . . . ±15mA
ILF Fault Output Current . . . . . ±15mA
Output Load Current, (Self Limiting, See Elec. Spec.). . . . $\pm I_{O(LIMIT)}$

Operating Conditions T_A = 25°C

Typical Operating Supply Voltage Range, V_{DD} . . . . . +3 to +12V
Low Voltage Logic Retention, Min. V_{DD}. . . . . +2V
Idle Supply Current; No Load, V_{DD} = +5V. 0.8mA
Typical P+N Channel $r_{DS(ON)}$, V_{DD} = +5V, 0.5A Load 2Ω

Thermal Information

Thermal Resistance (Typical, Note 2)	θ_{JA} (°C/W)
Plastic SOIC Package	105

Maximum Storage Temperature Range . . . . . -65°C to 150°C
Maximum Junction Temperature . . . . . 150°C
Maximum Lead Temperature (Soldering 10s) . . . . . 300°C
(Lead Tips Only)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

1. V_{SS} is the required common ground reference for the logic input switching. The load currents may be switched positive and negative in reference to the V_{SS} common ground by using a split supply for V_{DD} (positive) to V_{SSA} and V_{SSB} (negative). For an uneven split in the supply voltage, the Maximum Negative Output Supply Voltage for V_{SSA} and V_{SSB} is limited by the Maximum V_{DD} to V_{SSA} or V_{SSB} ratings. Since the V_{DD} pins are internally tied together, the voltage on each V_{DD} pins must be equal and common.
2. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.
3. Refer to the Truth Table and the V_{EN} to V_{OUT} Switching Waveforms. Current, I_O refers to I_{OUTA} or I_{OUTB} as the Output Load current. Note that ENA controls OUTA and ENB controls OUTB. Each Half H-Switch has independent control from the respective A1, A2, ENA or $\overline{B1}$, B2, ENB inputs. Refer to the Terminal Information Table for external pin connections to establish mode control switching. Figure 1 shows a typical application circuit used to control a DC Motor.

Electrical Specifications T_A = 25°C, V_{DD} = +5V, V_{SSA} = V_{SSB} = V_{SS} = 0V, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Input Leakage Current	I_{LEAK}	V_{DD} = +15V	-	-	25	nA
Low Level Input Voltage	V_{IL}		V_{SS}	-	0.8	V
High Level Input Voltage	V_{IH}		2	-	V_{DD}	V
ILF Output Low, Sink Current	I_{OH}	V_{OUT} = 0.4V, V_{DD} = +12V	15	-	-	mA
ILF Output High, Source Current	I_{OL}	V_{OUT} = 11.6V, V_{DD} = +12V	-	-	-15	mA
Input Capacitance	C_{IN}		-	2	-	pF
P-Channel $r_{DS(ON)}$, Low Supply Voltage	$r_{DS(ON)}$	V_{DD} = +3V, I_{SOURCE} = 250mA	-	1.6	2.1	Ω
N-Channel $r_{DS(ON)}$, Low Supply Voltage	$r_{DS(ON)}$	V_{DD} = +3V, I_{SINK} = 250mA	-	1	1.5	Ω
P-Channel $r_{DS(ON)}$, High Supply Voltage	$r_{DS(ON)}$	V_{DD} = +12V, I_{SOURCE} = 400mA	-	0.6	1.2	Ω
N-Channel $r_{DS(ON)}$, High Supply Voltage	$r_{DS(ON)}$	V_{DD} = +12V, I_{SINK} = 400mA	-	0.5	1.1	Ω
OUTA, OUTB Source Current Limiting	$I_{O(LIMIT)}$	V_{DD} = +6V, V_{SS} = 0V, V_{SSA} = V_{SSB} = -6V	480	625	1500	mA
OUTA, OUTB Sink Current Limiting	$-I_{O(LIMIT)}$	V_{DD} = +6V, V_{SS} = 0V, V_{SSA} = V_{SSB} = -6V	480	800	1500	mA
Idle Supply Current; No Load	I_{DD}		-	0.8	1.5	mA
OUTA, OUTB Voltage High	V_{OH}	I_{SOURCE} = 450mA	4.2	4.5	-	V
OUTA, OUTB Voltage Low	V_{OL}	I_{SINK} = 450mA	-	0.4	0.6	V
OUTA, OUTB Voltage High	V_{OH}	V_{DD} = +3V, I_{SOURCE} = 250mA	2.415	2.6	-	V
OUTA, OUTB Voltage Low	V_{OL}	V_{DD} = +3V, I_{SINK} = 250mA	-	0.25	0.375	V
OUTA, OUTB Source Current Limiting	$I_{O(LIMIT)}$	V_{DD} = +12V	480	625	1500	mA
OUTA, OUTB Sink Current Limiting	$-I_{O(LIMIT)}$	V_{DD} = +12V	480	800	1500	mA
OUTA, OUTB Source Current Limiting	$I_{O(LIMIT)}$	V_{DD} = +3V	480	625	1500	mA
OUTA, OUTB Sink Current Limiting	$-I_{O(LIMIT)}$	V_{DD} = +3V	480	800	1500	mA

Electrical Specifications $T_A = 25°C$, $V_{DD} = +5V$, $V_{SSA} = V_{SSB} = V_{SS} = 0V$, Unless Otherwise Specified **(Continued)**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Thermal Shutdown	T_{SD}		-	145	-	°C
Response Time: V_{EN} to V_{OUT} Turn-On: Prop Delay	t_{PLH}	$I_O = 0.5A$ (Note 3)	-	2.5	-	µs
Rise Time	t_r		-	4	-	µs
Turn-Off: Prop Delay	t_{PHL}		-	0.1	-	µs
Fall Time	t_f		-	0.1	-	µs

Pin Descriptions

PIN NUMBER	SYMBOL	DESCRIPTION
12, 19	V_{DD}	Positive Power Supply pins; internally common and externally connect to the same Positive Supply (V+).
15	V_{SSA}	Negative Power Supply pin; Negative or Ground return for Switch Driver A; externally connect to the Supply (V-).
16	V_{SSB}	Negative Power Supply pin; Negative or Ground return for Switch Driver B; externally connect to the Supply (V-).
6	V_{SS}	Common Ground pin for the Input Logic Control circuits. May be used as a common ground with V_{SSA} and V_{SSB}.
8, 5	A1, $\overline{B1}$	Input pins used to control the direction of output load current to/from OUTA and OUTB, respectively. When connected, A1 and $\overline{B1}$ can be controlled from the same logic signal to change the directional rotation of a motor.
9, 3	A2, B2	Input pins used to force a low state on OUTA and OUTB, respectively. When connected, A2 and B2 can be controlled from the same logic signal to activate Dynamic Braking of a motor.
7, 4	ENA, ENB	Input pins used to Enable Switch Driver A and Switch Driver B, respectively. When Low, the respective output is in a high impedance (Z) off-state. Since each Switch Driver is independently controlled, OUTA and OUTB may be a separately PWM controlled as Half H-Switch Drivers.
14, 17	OUTA, OUTB	Respectively, Switch Driver A and Switch Driver B Output pins.
2	ILF	Current Limiting Fault Output Flag pin; when in a high logic state, signifies that Switch Driver A or B or both are in a Current Limiting Fault Mode.

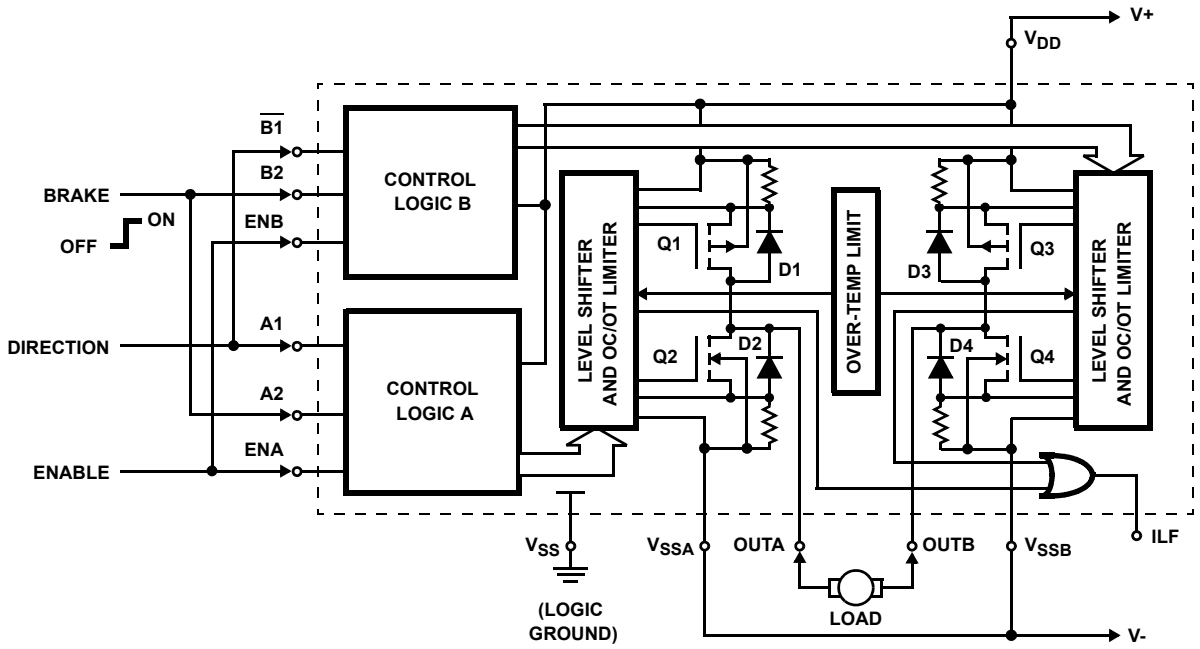
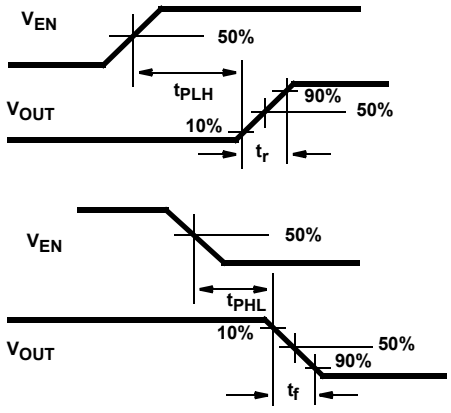


FIGURE 1. TYPICAL MOTOR CONTROL APPLICATION CIRCUIT SHOWING DIRECTIONAL AND BRAKING CONTROL

TRUTH TABLE

SWITCH DRIVER A				SWITCH DRIVER B			
INPUTS			OUTPUT	INPUTS			OUTPUT
A1	A2	ENA	OUTA	$\overline{B1}$	B2	ENB	OUTB
H	L	H	OH	L	L	H	OH
L	L	H	OL	H	L	H	OL
H	H	H	OL	L	H	H	OL
L	H	H	OL	H	H	H	OL
X	X	L	Z	X	X	L	Z

L = Low logic level; H = High logic level
Z = High Impedance (off state)
OH = Output High (sourcing current to the output terminal)
OL = Output Low (sinking current from the output terminal)
X = Don't Care



SWITCHING WAVEFORMS

FIGURE 2.

Application

The HIP4020 is designed to detect load current feedback from sampling resistors of low value in the source connections of the output drivers to V_{DD}, V_{SSA} and V_{SSB} (See Figure 1). When the sink or source current at OUTA or OUTB exceeds the preset OC (Overcurrent) limiting value of 550mA typical, the current is held at the limiting value. If the OT (Over-Temperature) Shutdown Protection limit is exceeded, temperature sensing BiMOS circuits limit the junction temperature to 150°C typical.

The circuit of Figure 1 shows the Full H-Switch in a small motor-drive application. The left (A) and right (B) H-Switch's are controlled from the A and B inputs via the A and B CONTROL LOGIC to the MOS output transistors Q1, Q2, Q3 and Q4. The circuit is intended to safely start, stop, and control rotational direction for a motor requiring no more than 0.5A of supply current. The stop function includes a Dynamic Braking feature.

With the ENABLE Inputs Low, the MOS transistors Q1 and Q3 are OFF; which cuts-off supply current to OUTA and OUTB. With the BRAKE terminal Low and ENABLE Inputs High, either Q1 and Q4 or Q3 and Q2 will be driven into conduction by the

DIRECTION Input Control terminal. The MOS output transistor pair chosen for conduction is determined by the logic level applied to the DIRECTION control; resulting in either clockwise (CW) or counter-clockwise (CCW) shaft rotation.

When the BRAKE terminal is switched high (while holding the ENABLE input high), the gates of both Q2 and Q4 are driven high. Current flowing through Q2 (from the motor terminal OUTA) at the moment of Dynamic Braking will continue to flow through Q2 to the V_{SSA} and V_{SSB} external connection, and then continue through diode D4 to the motor terminal OUTB. As such, the resistance of the motor winding (and the series-connected path) dissipates the kinetic energy stored in the system. Reversing rotation, current flowing through Q4 (from the motor terminal OUTB), at the moment of Dynamic Braking, would continue to flow through Q4 to the V_{SSB} and V_{SSA} tie, and then continue through diode D2 to the motor terminal OUTA, to dissipate the stored kinetic energy as previously described.

Where V_{DD} to V_{SS} are the Power Supply reference terminals for the Control Logic, the lowest practical supply voltage for proper logic control should be no less than 2.0V. The V_{SSA} and V_{SSB} terminals are separate and independent from V_{SS} and may be more negative than the V_{SS} ground reference terminal. However, the maximum supply level from V_{DD} to V_{SSA} or V_{SSB} must not be greater than the Absolute Maximum Supply Voltage rating.

Terminals A1, $\overline{B1}$, A2, B2, ENA and ENB are internally connected to protection circuits intended to guard the CMOS gate-oxides against damage due to electrostatic discharge. (See Figure 3) Inputs ENA, ENB, A1, $\overline{B1}$ A2 and B2 have CD74HCT4000 Logic Interface Protection and Level Converters for TTL or CMOS Input Logic. These inputs are designed to typically provide ESD protection up to 2kV. However, these devices are sensitive to electrostatic discharge. Proper I.C. handling procedures should be followed.

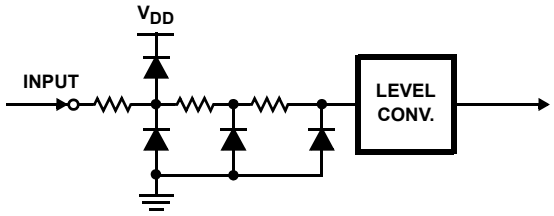


FIGURE 3. LOGIC INPUT ESD INTERFACE PROTECTION

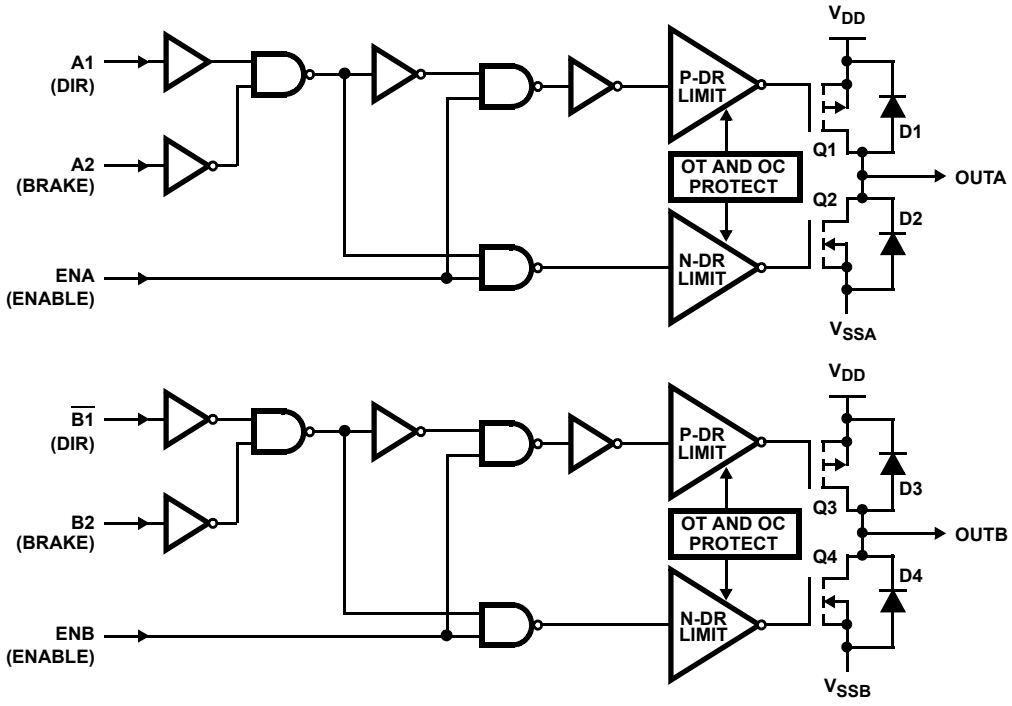


FIGURE 4. EQUIVALENT CONTROL LOGIC A AND B SHOWN DRIVING THE OUTA AND OUTB OUTPUT DRIVERS

Typical Performance Curves

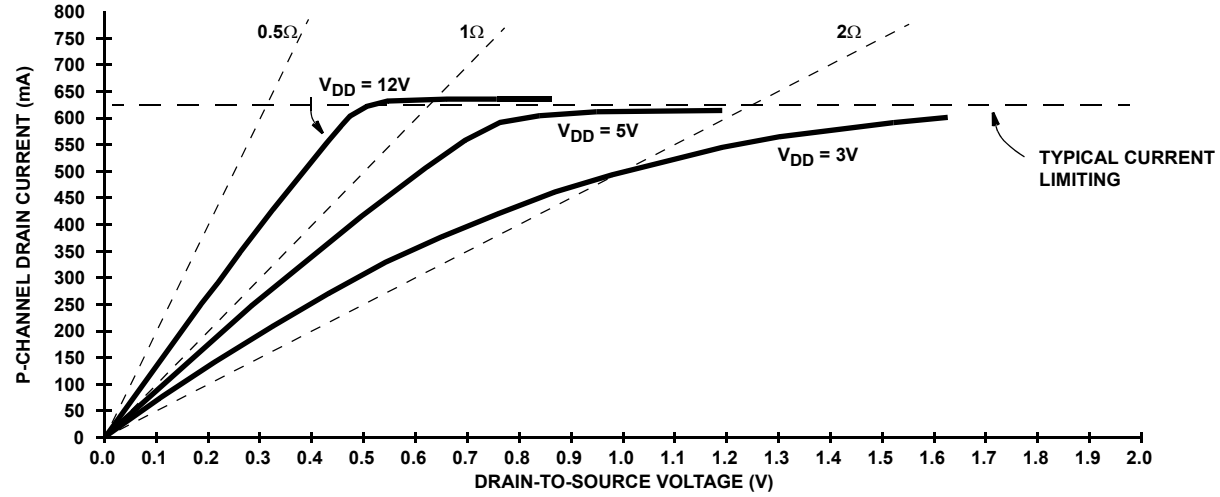


FIGURE 5. TYPICAL CHARACTERISTIC OF THE P-MOSFET OUTPUT DRIVER DRAIN CURRENT vs DRAIN-TO-SOURCE VOLTAGE, $T_{AMBIENT}$ = 25°C

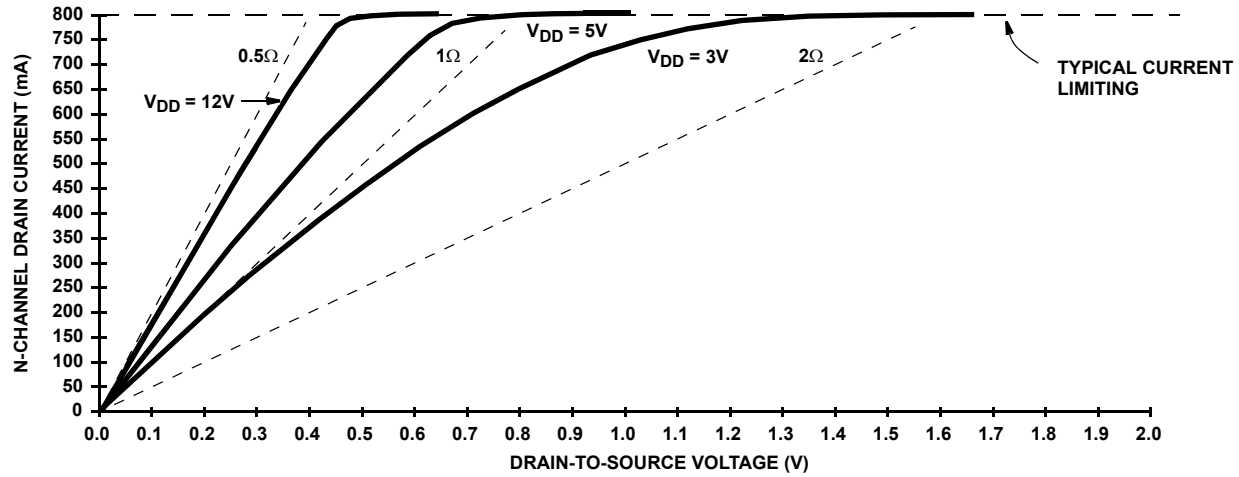


FIGURE 6. TYPICAL CHARACTERISTIC OF THE N-MOSFET OUTPUT DRIVER DRAIN CURRENT vs DRAIN-TO-SOURCE VOLTAGE, $T_{AMBIENT}$ = 25°C

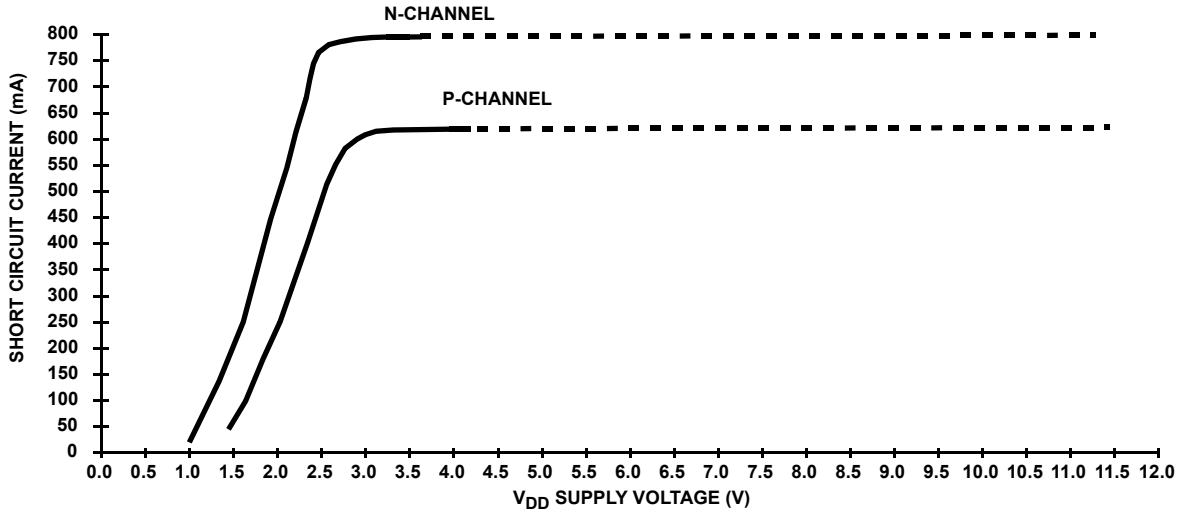


FIGURE 7. TYPICAL CHARACTERISTIC OF THE P AND N OUTPUT DRIVER SHORT CIRCUIT CURRENT vs SUPPLY VOLTAGE, $T_{AMBIENT}$ = 25°C

Typical Performance Curves (Continued)

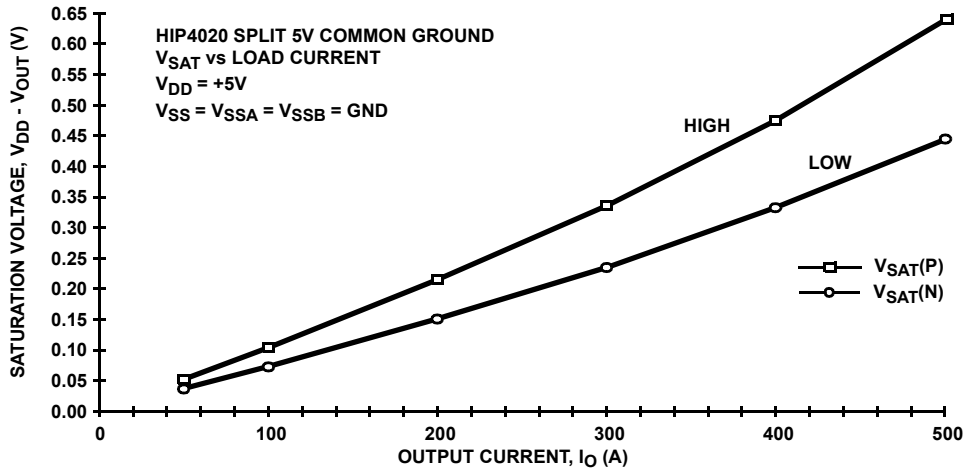


FIGURE 8. TYPICAL CHARACTERISTIC OF SATURATION VOLTAGE vs OUTPUT CURRENT USING A +5V SUPPLY, $T_{AMBIENT}$ = 25°C

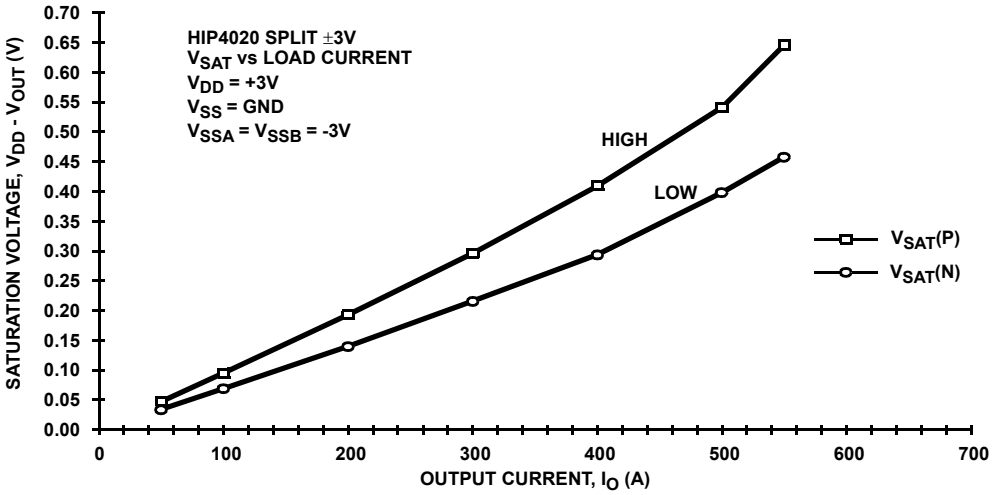


FIGURE 9. TYPICAL CHARACTERISTIC OF SATURATION VOLTAGE vs OUTPUT CURRENT USING A ±3V SPLIT SUPPLY, OUTPUT REFERENCE EQUAL LOGIC GROUND, $T_{AMBIENT}$ = 25°C

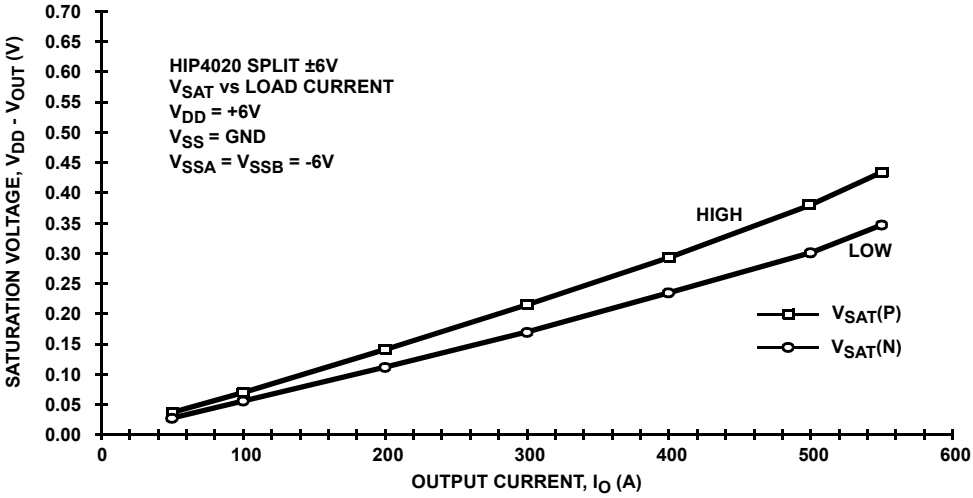


FIGURE 10. TYPICAL CHARACTERISTIC OF SATURATION VOLTAGE vs OUTPUT CURRENT USING A ±6V SPLIT SUPPLY, OUTPUT REFERENCE EQUAL LOGIC GROUND, $T_{AMBIENT}$ = 25°C

Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to the web to make sure that you have the latest revision.

DATE	REVISION	CHANGE
September 17, 2015	FN3976.4	- Updated Ordering Information Table on page 1. - Added Revision History. - Added About Intersil Verbiage. - Updated POD M20.3 to latest revision changes are as follow: Top View: Corrected "7.50 BSC" to "7.60/7.40" (no change from rev 2; error was introduced in conversion) Changed "10.30 BSC" to "10.65/10.00" (no change from rev 2; error was introduced in conversion) Side View: Changed "12.80 BSC" to "13.00/12.60" (no change from rev 2; error was introduced in conversion) Changed "2.65 max" to "2.65/2.35" (no change from rev 2; error was introduced in conversion) Changed Note 1 from "ANSI Y14.5M-1982." to "ASME Y14.5M-1994"

About Intersil

Intersil Corporation is a leading provider of innovative power management and precision analog solutions. The company's products address some of the largest markets within the industrial and infrastructure, mobile computing and high-end consumer markets.

For the most updated datasheet, application notes, related documentation and related parts, please see the respective product information page found at www.intersil.com.

You may report errors or suggestions for improving this datasheet by visiting www.intersil.com/ask.

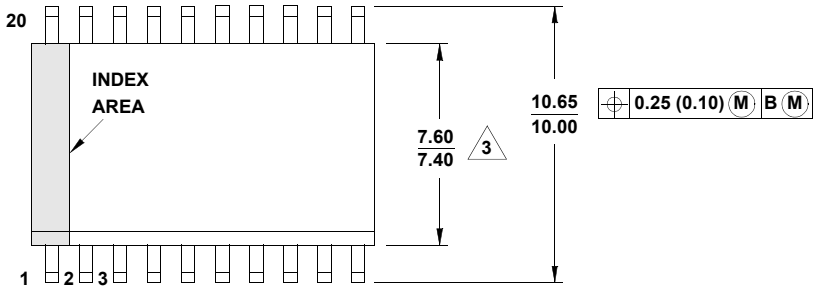
Reliability reports are also available from our website at www.intersil.com/support.

Package Outline Drawing

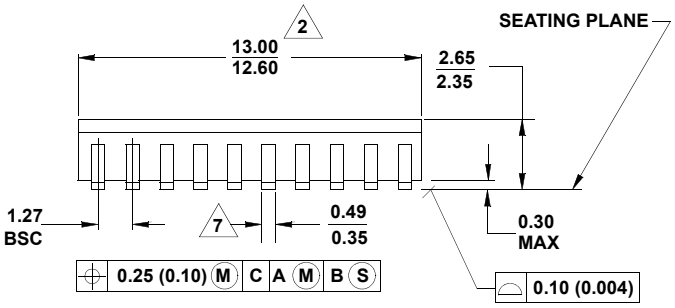
M20.3

20 LEAD WIDE BODY SMALL OUTLINE PLASTIC PACKAGE (SOIC)

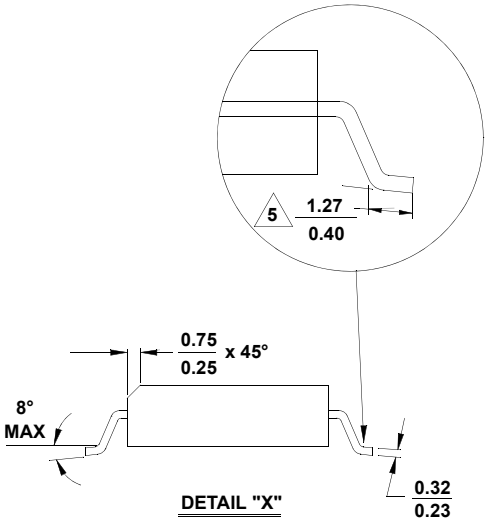
Rev 3, 2/11



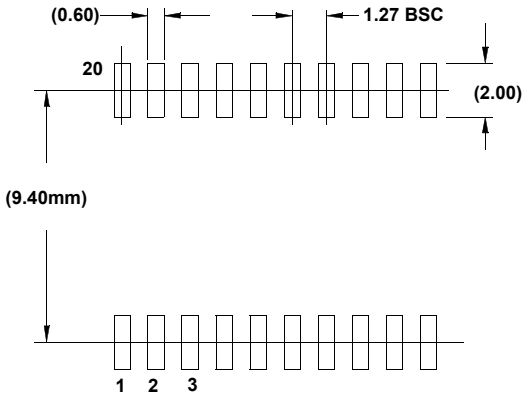
TOP VIEW



SIDE VIEW



DETAIL "X"



TYPICAL RECOMMENDED LAND PATTERN

NOTES:

1. Dimensioning and tolerancing per ASME Y14.5M-1994.
2. Dimension does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
3. Dimension does not include interlead lash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
4. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
5. Dimension is the length of terminal for soldering to a substrate.
6. Terminal numbers are shown for reference only.
7. The lead width as measured 0.36mm (0.14 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch)
8. Controlling dimension: MILLIMETER.
9. Dimensions in ( ) for reference only.
10. JEDEC reference drawing number: MS-013-AC.